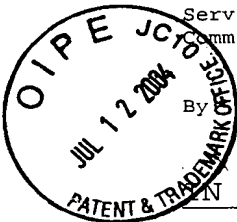


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Docket No.: P2001,0216

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to the Commissioner for Patents, Alexandria, VA 22313-1450



By

Date: July 8, 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applic. No. : 10/673,705 Conf. No.: 2451
Applicant : Annalisa Cappellani et al.
Filed : September 26, 2003
Title : Method for Fabricating a MOSFET Having a
Very Small Channel Length
TC/A.U. : 2829
Examiner : Scott B. Geyer
Customer No. : 24131

Hon. Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

A M E N D M E N T

S i r :

Responsive to the Office action dated June 16, 2004, kindly
amend the above-identified application as follows.

Amendments to the Abstract begin on page 2 of this paper.

Amendments to the Drawings begin on page 3 of this paper.

Remarks/Arguments begin on page 4 of this paper.